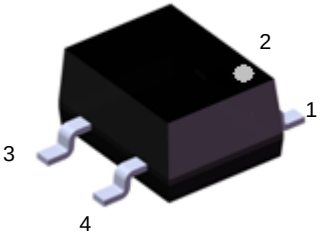
EVERLIGHT AMERICAS

DATASHEET

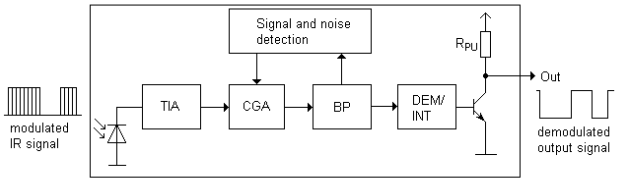
Infrared Remote Control Receiver Module
EAIRMKA1 & EAIRMKA2



Pin Configuration

1. GND
2. GND
3. OUT
4. Vcc

Block Diagram



Features

- High protection ability against EMI
- Available for various carrier frequencies
- Min burst length: 10 cycles
- Min gap length: 14 cycles
- Low operating voltage and low power consumption
- High immunity against ambient light
- Long reception range
- High sensitivity
- Pb free and RoHS compliant
- Compliance with EU REACH
- Compliance Halogen Free .(Br <900 ppm ,Cl <900 ppm , Br+Cl < 1500 ppm)

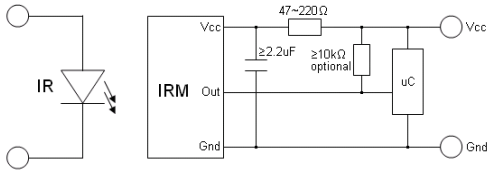
Descriptions

- The device is miniature SMD type infrared receiver that has been developed and designed by utilizing the latest IC technology.
- The PIN diode and preamplifier are assembled onto a lead frame and molded into a black epoxy package which operates as an IR filter. The demodulated output signal can directly be decoded by a microprocessor

Applications

- Light detecting portion of remote control
- AV instruments such as Audio, TV, VCR, CD, MD, etc
- Home appliances such as Air-conditioner, Fan, etc
- 0ther devices using IR remote control
- CATV set top boxes
- Multi-media Equipment

Application Circuit



RC Filter should be connected closely between Vcc pin and GND pin.

Parts Table

Model No.	Carrier Frequency
EAIRMKA1	36 kHz
EAIRMKA2	38 kHz

Absolute Maximum Ratings (T_a=25°C)

Parameter	Symbol	Rating	Unit
Supply Voltage	Vs	6	V
Operating Temperature	Topr	-20 ~ +80	℃
Storage Temperature	Tstg	-40 ~ +85	℃
Soldering Temperature *1	Tsol	260	℃

*1 4mm from mold body less than 5 seconds

Electro-Optical Characteristics (Ta=25℃ and Vcc=3.0V)

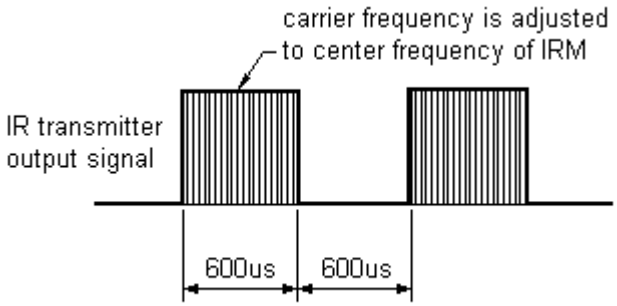
Parameter	Symbol	MIN.	TYP.	MAX.	Unit	Condition
Current Consumption	Icc	-	0.4	0.6	mA	No signal input
Supply Voltage	Vs	2.7	-	5.5	V	
Peak Wavelength	λ_p	-	940	-	nm	
Reception Distance	L_0	8	-	-	m	See chapter ‚Test method'
	L_{45}	5	-	-		
Half Angle (Horizontal)	Θ_h	-	45	-	deg	
Half Angle (Vertical)	Θ_v	-	45	-	deg	
High Level Pulse Width	T_{WH}	450	-	750	μs	Test signal according to figure 1
Low Level Pulse Width	T_{WL}	450	-	750	μs	
High Level Output Voltage	V_H	Vcc-0.4	-	-	V	
Low Level Output Voltage	V_L	-	0.2	0.5	V	$I_{SINK} \leqq 2mA$
Internal pull up resistor	R_{PU}	85	100	115	kΩ	

Test Method

The specified electro-optical characteristic is satisfied under the following Conditions:

1. Measurement environment
   A place without extreme light reflected
2. External light
   Ordinary white fluorescent lamps (Light source temperature 2856°K, Ee≦10Lux) without high frequency modulation
3. Standard transmitter
   The test transmitter is calibrated by using the circuit shown in figure 2. The radiation intensity of the transmitter is adjusted until **Vo=400mVp-p.** Both, the test transmitter and the photo diode, have a peak wavelength of 940nm. The photo diode for calibration is PD438B (λp=940nm, Vr=5V).
4. Measuring system According to the measuring system shown in Fig.-3

Fig.-1 Transmitter Wave Form



D.U.T output Pulse

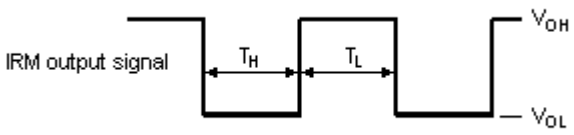


Fig.-2 Measuring Method

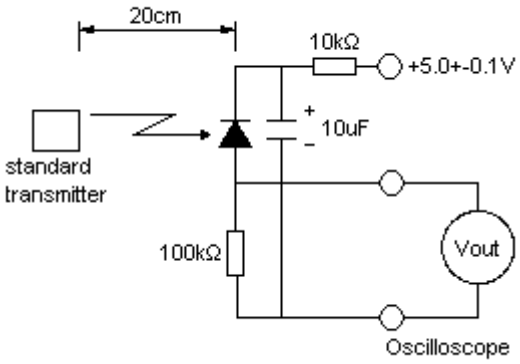
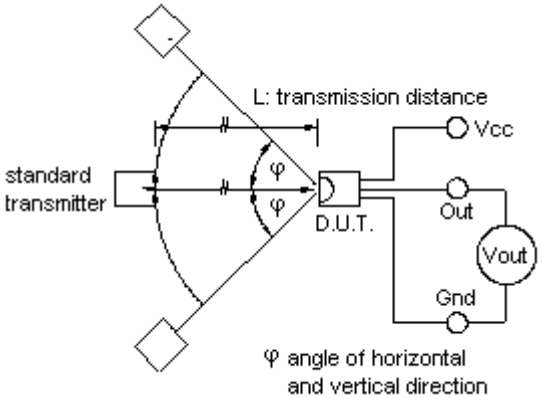


Fig.-3 Measuring System



Typical Performance Curves

Fig.4 Relative Responsibility vs. Wavelength

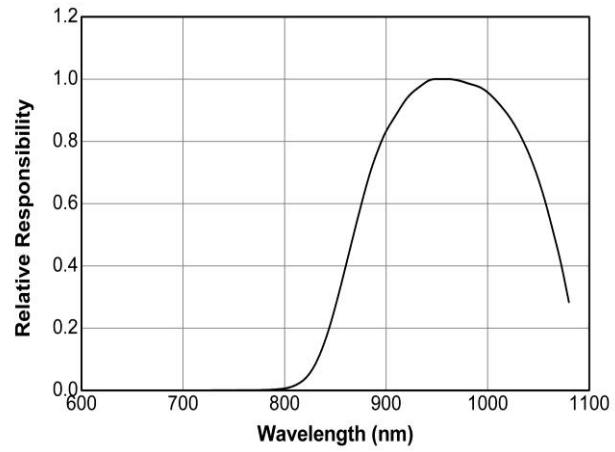


Fig.-5 Relative Transmission Distance vs. Direction

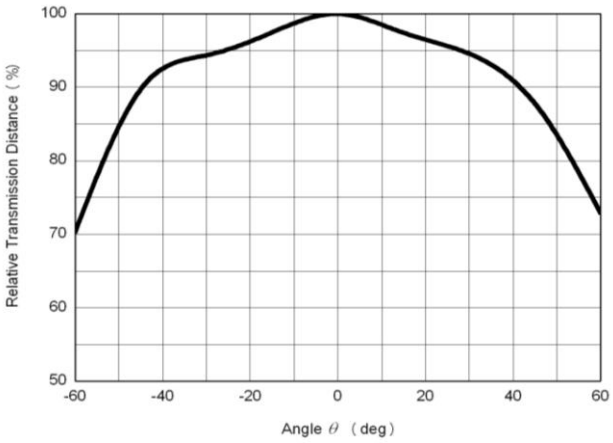


Fig.6 Variation Output Pulse Width vs. Distance

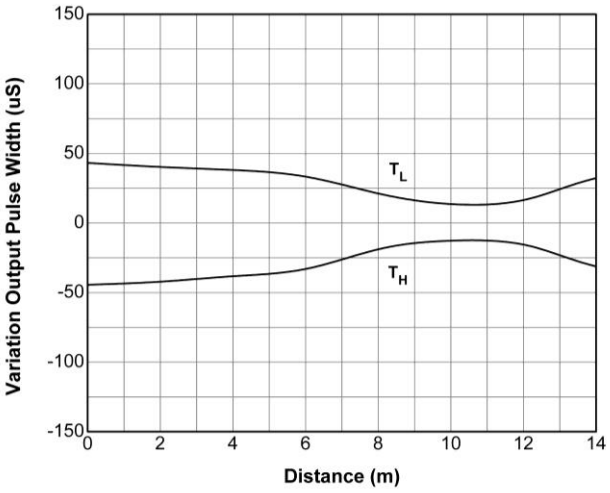


Fig.7 Relative Sensitivity vs. Supply Voltage

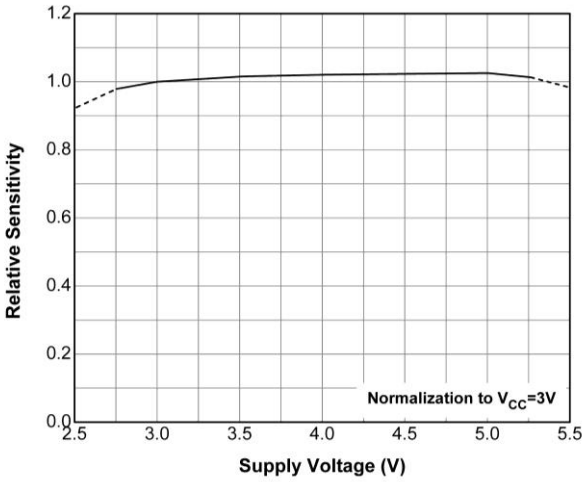
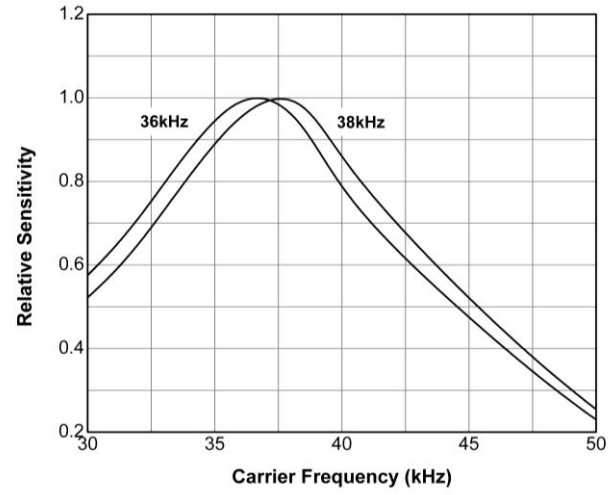
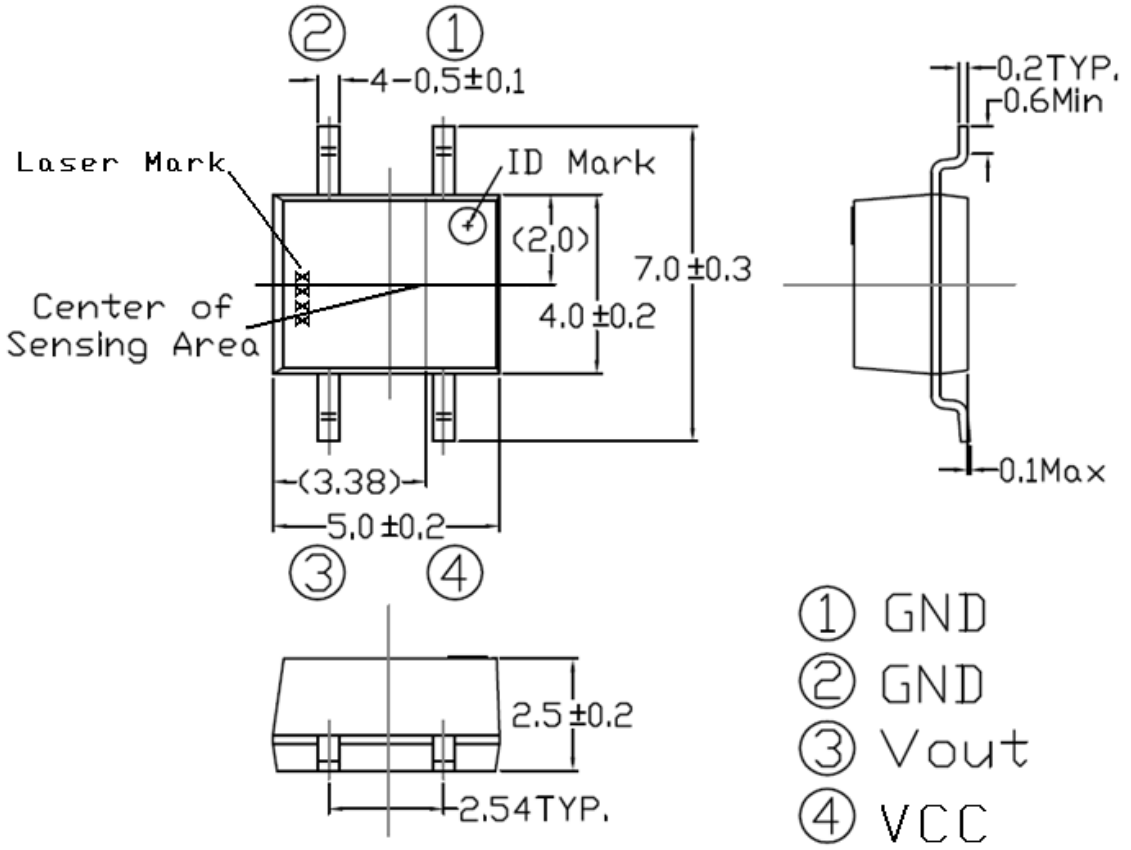


Fig.8 Relative Sensitivity vs. Carrier Frequency

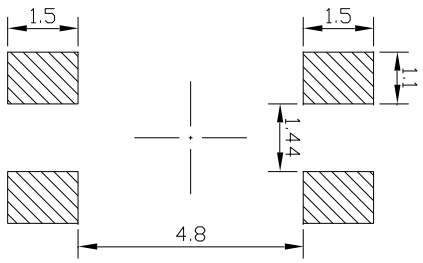


Package Dimenstions

(Dimensions in mm)



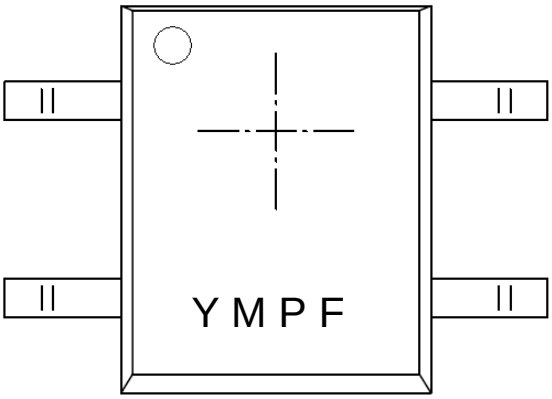
Recommended pad layout for surface mount leadform



Code information

Protocol	Suitable	Protocol	Suitable
JVC	Yes	RCA	No
Matsushita	Yes	Sharp	Yes
Mitsubishi	No	Sony 12 Bit	Yes
NEC	Yes	Sony 15 Bit	No
RC5	Yes	Sony 20 Bit	No
RC6	Yes	Toshiba	Yes
RCMM	No	XMP-1	Yes
RCS-80	No	Continuous Code	No

Device Marking



Notes

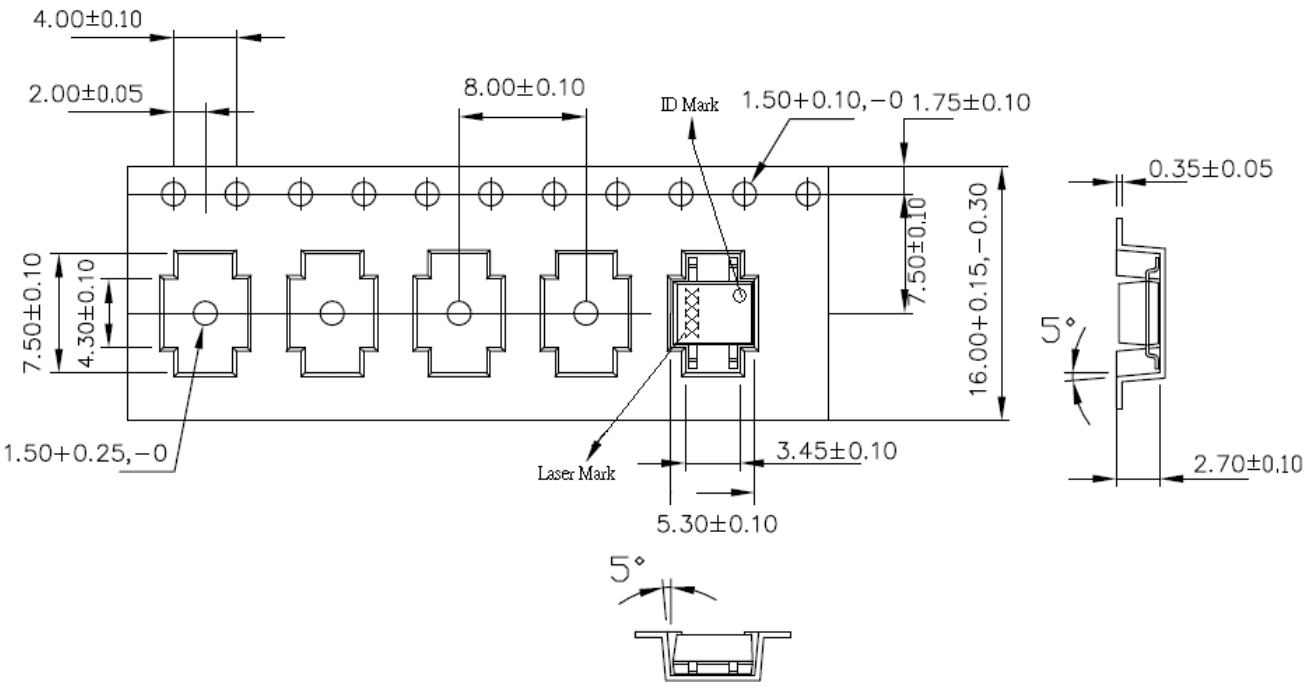
Y denotes Years code

M denotes Month code

P denotes Device number

F denotes Carrier frequency (2: 36KHz, 4: 38KHz)

Tape & Reel Packing Specifications

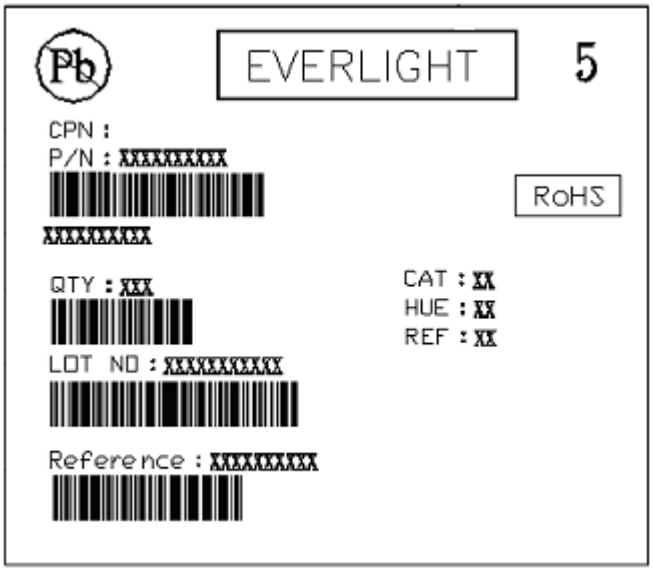


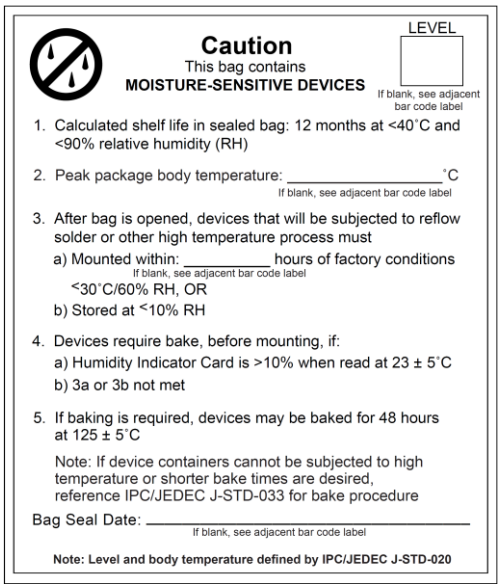
Packing Quantity

1000 pcs / Reel

5 Reels / Carton

Label format





Moisture Classification-storage and used condition label

Recommended method of storage

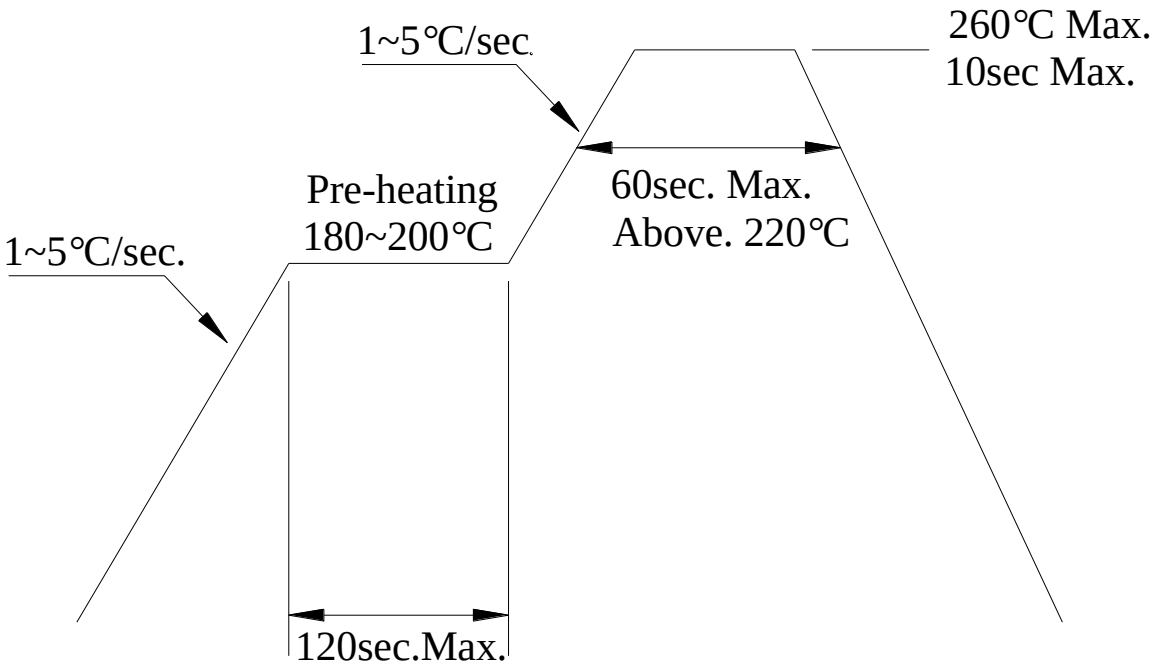
The following are general recommendations for moisture sensitive level (MSL) 4 storage and use:

1. Shelf life in sealed bag from the bag seal date: 12 months at < 40 °C and < 90% relative humidity (RH)
2. After bag is opened, devices that will be subjected to reflow solder or other high temperature process must mounted within 72 hours of factory conditions < 30 °C/60%RH.
3. If the moisture absorbent material (silica gel) has faded away or the IRM has exceeded the storage time. Baking treatment is required, refer to IPC/JEDEC J-STD-033 for bake procedure or recommend the conditions: 60±5°C for 96 hours.

ESD Precaution

Proper storage and handing procedures should be followed to prevent ESD damage to the devices especially when they are removed from the Anti-static bag. Electro-Static Sensitive Devices warning labels are on the packing.

Solder Reflow Temperature Profile



Note:

1. Reflow soldering should not be done more than two times.
2. When soldering, do not put stress on the IRM device during heating.
3. After soldering, do not warp the circuit board.

DISCLAIMER

1. Everlight Americas will reserve the right to make changes on specification and material but with notice.
2. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. Everlight Americas assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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